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	Filing Date		2005-06-10	
	First Named Inventor	Shi Xue Duo et al.		
	Art Unit	1796		
	Examiner Name	Mark T. Kopec		
Attorney Docket Number		7383/83836		

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1	S. X. DOU et al., "Superconductivity, critical current density and flux pinning in MgB _{2-x} (SiC) _x /2. superconductor after SiC nanoparticle doping", Journal of Applied Physics, Vol. 94, Issue 3, August 2003, pp. 1850-1856.	<input type="checkbox"/>
2	C. H. JIANG and H. KUMAKURA, "Stoichiometry dependence of the critical current density in pure and non-SiC doped MgB _{2-x} /Fe tapes", Physica C: Superconductivity, Vol. 451, Issue 1, January 2007, pp. 71-76.	<input type="checkbox"/>

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